

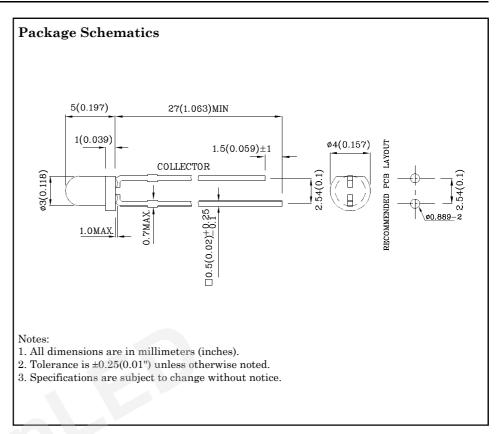
# PHOTOTRANSISTOR

# **Features**

- Radial / Through hole package
- Reliable & robust
- Low power consumption
- RoHS Compliant







# Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Condiction
VBR CEO	Collector-to-Emitter Breakdown Voltage	30			V	Ic=100µA Ee=0mW/cm²
VBR ECO	Emitter-to-Collector Breakdown Voltage	5			V	IE=100μA Ee=0mW/cm²
VCE(SAT)	Collector-to-Emitter Saturation Voltage			0.8	V	IC=2mA Ee=20mW/cm <sup>2</sup>
ICEO	Collector Dark Current			100	nA	VCE=10V Ee=0mW/cm <sup>2</sup>
TR	Rise Time (10% to 90%)		15		μs	Vce=5V Ic=1mA Rl=1KΩ
TF	Fall Time (90% to 10%)		15		μs	
I(ON)	On State Collector Current	0.3	0.8		mA	$V_{\rm CE=5V}$ $E_{\rm e=1} m \text{W/cm}^2$ $\lambda=940 n m$

# Absolute Maximum Ratings at TA=25°C

Parameter	Maximum Ratings		
Collector-to-Emitter Voltage	30V		
Emitter-to-Collector Voltage	5V		
Power Dissipation at (or below) 25°C Free Air Temperature	100mW		
Operating / Storage Temperature Range	-40°C To +85°C		
Lead Solder Temperature (>5mm for 5sec)	260°C		





Typical Electro-Optical Characteristics Curves

Fig.1 Collector Power Dissipation vs.
Ambient Temperature

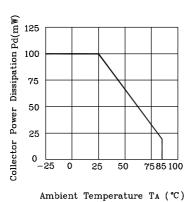


Fig.2 Spectral Sensitivity

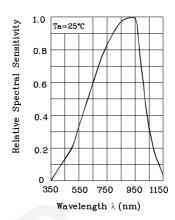


Fig. 3 Relative Collector Current vs.
Ambient Temperature

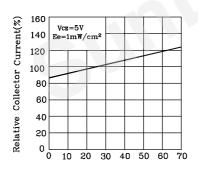


Fig. 4 Collector Current vs. Irradiance

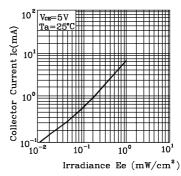


Fig.5 Collector Dark Current vs.

Ambient Temperature

Ambient Temperature TA (°C)

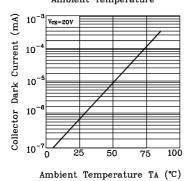
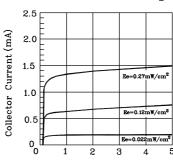


Fig.6 Collector Current vs.
Collector-Emitter Voltage

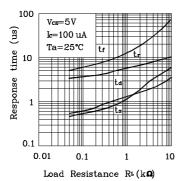


 ${\tt Collector-Emitter\ Voltage\ V_{CE}\ (V)}$ 

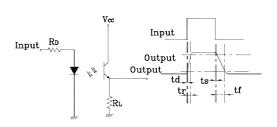




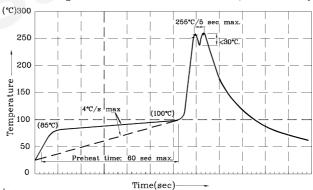
Fig.7 Response Time vs. Load Resistance



Test Circuit for Response Time



Wave Soldering Profile For Thru-Hole Products (Pb-Free Components)



- Notes. 1. Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C 2.Peak wave soldering temperature between 245°C  $\sim$  255°C for 3 sec (5 sec max).
- (5 sec max).

  3.Do not apply stress to the epoxy resin while the temperature is above 85°C.

  4.Fixtures should not incur stress on the component when mounting and during soldering process.

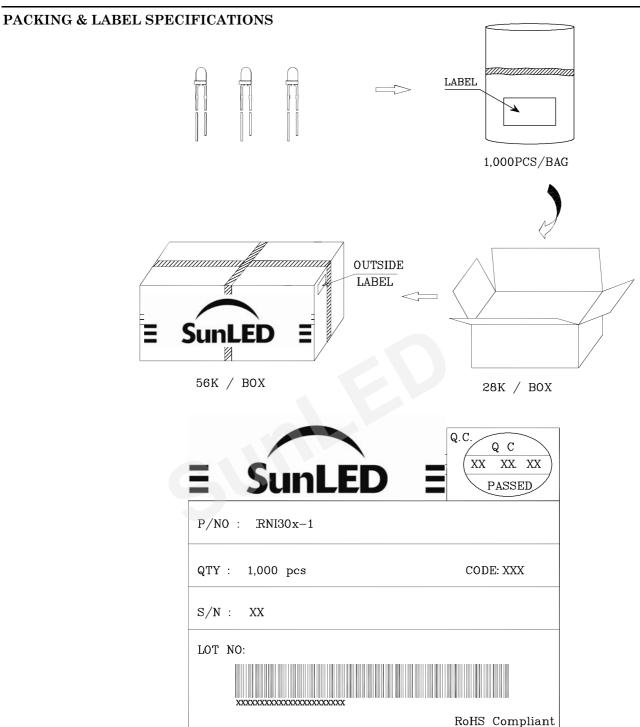
  5.SAC 305 solder alloy is recommended.

  6.No more than one wave soldering pass.



# Part Number: RNI30W-1

# PHOTOTRANSISTOR



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